

FPAB30PH60

Smart Power Module for Front-End Rectifier

General Description

FPAB30PH60 is an advanced smart power module of PFC(Power Factor Correction) that Fairchild has newly developed and designed mainly targeting mid-power application especially for an air conditioners. It combines optimized circuit protection and drive IC matched to high frequency switching IGBTs. System reliability is futher enhanced by the integrated under-voltage lock-out and over-current protection function.

Features

- Low thermal resistance due to Al_2O_3 -DBC substrate
- 600V-30A 2-phase IGBT PWM semi-converter including a drive IC for gate driving and protection
- Typical switching frequency of 20kHz
- Isolation rating of 2500Vrms/min.

Applications

• AC 180V ~ 264V single-phase front-end rectifier

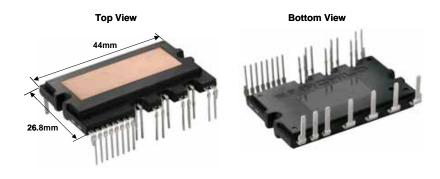


Fig. 1.

Integrated Power Functions

• PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

Integrated Drive, Protection and System Control Functions

- For IGBTs: Gate drive circuit, Overcurrent circuit protection (OC), Control supply circuit under-voltage (UV) protection
- Fault signaling: Corresponding to a UV fault
- Input interface: 5V CMOS/LSTTL compatible, Schmitt trigger input

Pin Configuration

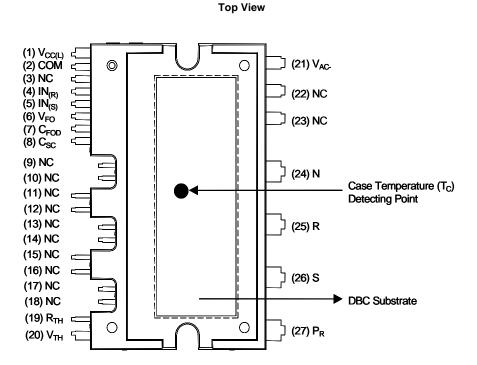
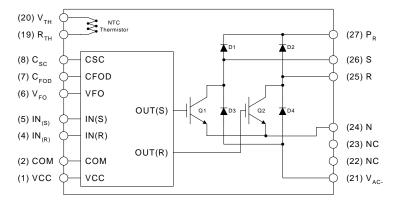


Fig. 2.

Pin Descriptions

Pin Number	Pin Name	Pin Description	
1	V _{CC}	Common Bias Voltage for IC and IGBTs Driving	
2	COM	Common Supply Ground	
4	IN _(R)	Signal Input for Low-side R-phase IGBT	
5	IN _(S)	Signal Input for Low-side S-phase IGBT	
6	V _{FO}	Fault Output	
7	C _{FOD}	Capacitor for Fault Output Duration Time Selection	
8	C _{SC}	Capacitor (Low-pass Filter) for Over Current Detection	
19	R _(TH)	NTC Thermistor terminal	
20	V _(TH)	NTC Thermistor terminal	
21	V _{AC-}	Negative Terminal of DC–Link (DIODE) for Sensing	
24	N	Negative Rail of DC–Link (IGBT)	
25	R	Output for R Phase	
26	S	Output for S Phase	
27	P_{R}	Positive Rail of DC–Link	
3, 9~18, 22~23	NC	No Connection	

Internal Equivalent Circuit and Input/Output Pins



Note:
1) Converter is composed of two IGBTs including four diodes and one IC which has gate driving and protection functions.

Fig. 3.

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Absolute Maximum Ratings ($T_J = 25$ °C, Unless Otherwise Specified)

Converter Part

Item	Symbol	Condition	Rating	Unit
Supply Voltage	V _i	Applied between R-S	264	V_{RMS}
Supply Voltage (Surge)	V _{i(Surge)}	Applied between R-S	500	V
Output Voltage	V _{PN}	Applied between P- N	450	V
Output Voltage (Surge)	V _{PN(Surge)}	Applied between P- N	500	V
Collector-emitter Voltage	V _{CES}		600	V
Input Current (100% Load)	l _i	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz	20	А
Input Current (125% Load)	l _{i(125%)}	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz, 1min Non-repetitive	25	А
Collector Dissipation	P _C	T _C = 25°C per One IGBT	83	W
Operating Junction Temperature	TJ	(Note 1)	-20 ~ 125	°C

Control Part

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V _{CC}	Applied between V _{CC} - COM	20	V
Input Signal Voltage	V _{IN}	Applied between IN - COM	-0.3~5.5	V
Fault Output Supply Voltage	V _{FO}	Applied between V _{FO} - COM	-0.3~V _{CC} +0.3	V
Fault Output Current	I _{FO}	Sink Current at V _{FO} Pin	5	mA
Current Sensing Input Voltage	V _{SC}	Applied between C _{SC} - COM	-0.3~V _{CC} +0.3	V

Total System

Item	Symbol	Condition	Rating	Unit
Module Case Operation Temperature	T _C		-20 ~ 100	°C
Storage Temperature	T _{STG}		-40 ~ 125	°C
Isolation Voltage	V _{ISO}	60Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V _{rms}

Thermal Resistance

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal	$R_{\theta(j-c)Q}$	IGBT	-	-	1.2	°C/W
Resistance	$R_{\theta(j-c)HD}$	High-side diode	-	-	2.0	°C/W
(Referenced to PKG center)	$R_{\theta(j-c)LD}$	Low-side diode	-	-	1.4	°C/W

Note : 2. For the measurement point of case temperature(T_C), please refer to Fig. 2.

Note 1. The maximum junction temperature rating of the power chips integrated within the SPM is 150 °C(@T_C \le 100°C). However, to insure safe operation of the SPM, the average junction temperature should be limited to $T_{J(ave)} \le 125$ °C (@T_C \le 100°C)

Electrical Characteristics (T_J = 25°C, Unless Otherwise Specified)

Converter Part

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
IGBT saturation voltage	$V_{CE(sat)}$	$V_{CC} = 15V, V_{IN} = 5V; I_{C} = 30A$	-	2.4	3.1	V
High-side diode voltage	V _{FH}	I _F = 30A	-	1.9	2.5	V
Low-side diode voltage	V_{FL}	I _F = 30A	-	1.2	1.6	V
Switching Times	t _{ON}	$V_{PN} = 400V$, $V_{CC} = 15V$, $I_{C} = 30A$ $V_{IN} = 0V \leftrightarrow 5V$, Inductive Load (Note 3)	-	550	-	ns
	t _{C(ON)}		-	200	-	ns
	t _{OFF}		-	430	-	ns
	t _{C(OFF)}	(New S)	-	180	-	ns
	t _{rr}		-	60	-	ns
	I _{rr}		-	6	-	Α
Collector - emitter Leakage Current	I _{CES}	V _{CE} = V _{CES}	-	-	250	μА

Control Part

Item	Symbol	Condition		Min.	Тур.	Max.	Unit
Quiescent V_{CC} Supply Current	I _{QCCL}	V _{CC} = 15V, IN = 0V	V _{CC} - COM	-	-	26	mA
Fault Output Voltage	V_{FOH}	V _{SC} = 0V, V _{FO} Circui	t: 4.7kΩ to 5V Pull-up	4.5	-	-	V
	V _{FOL}	V _{SC} = 1V, V _{FO} Circui	t: 4.7kΩ to 5V Pull-up	-	-	0.8	V
Over Current Trip Level	V _{SC(ref)}	V _{CC} = 15V	0.45	0.5	0.55	V	
Supply Circuit Under-	UV _{CCD}	Detection Level		10.7	11.9	13.0	V
Voltage Protection	UV _{CCR}	Reset Level		11.2	12.4	13.2	V
Fault-out Pulse Width	t _{FOD}	C _{FOD} = 33nF (Note 4	1.4	1.8	2.0	ms	
ON Threshold Voltage	V _{IN(ON)}	Applied between IN - COM		3.0	-	-	V
OFF Threshold Voltage	V _{IN(OFF)}	1	-	-	0.8	V	
Resistance of Thermistor	R _{TH}	@ T _C = 25°C (Note Fig. 9)		-	50	-	kΩ
		@ T _C = 80°C (Note F	Fig. 9)	-	5.76	-	kΩ

Note
3. t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. t_{C(ON)} and t_{C(OFF)} are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

Note 4. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD}[F]$

Electrical Characteristics

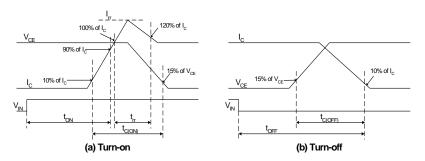


Fig. 4. Switching Time Definition

Mechanical Characteristics and Ratings

Item		Limits			Units	
item	Condition			Тур.	Max.	Ullis
Mounting Torque	Mounting Screw: - M3	Recommended 0.62N•m	0.51	0.62	0.72	N•m
Device Flatness	Note Fig. 5	0	-	+120	μm	
Weight			-	15.00	-	g

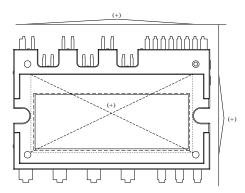
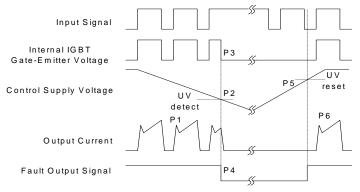


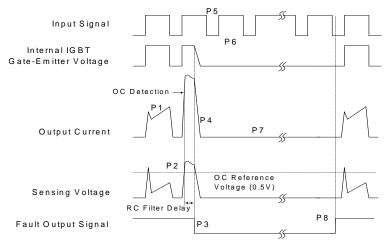
Fig. 5. Flatness Measurement Position

Time Charts of SPMs Protective Function



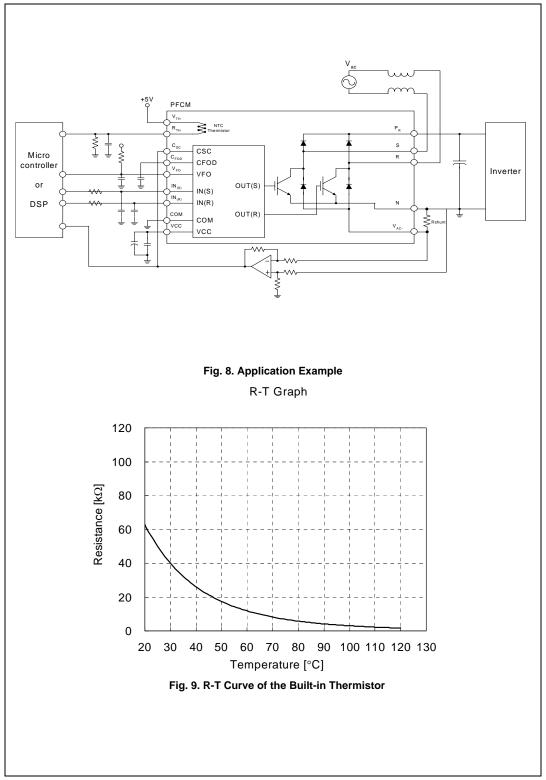
- P1: Normal operation IGBT ON and conducting current
- P2: Under voltage detection
- P3 : IGBT gate interrupt P4 : Fault signal generation
- P5 : Under voltage reset
- P6: Normal operation IGBT ON and conducting current

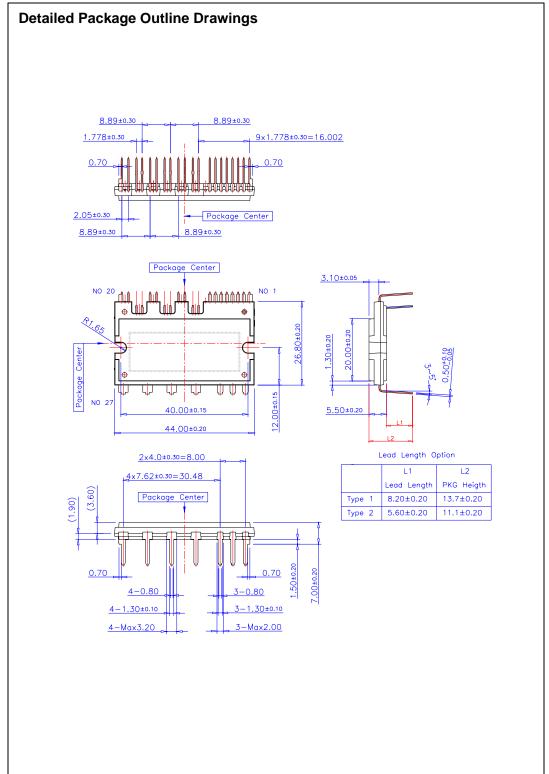
Fig. 6. Under-Voltage Protection

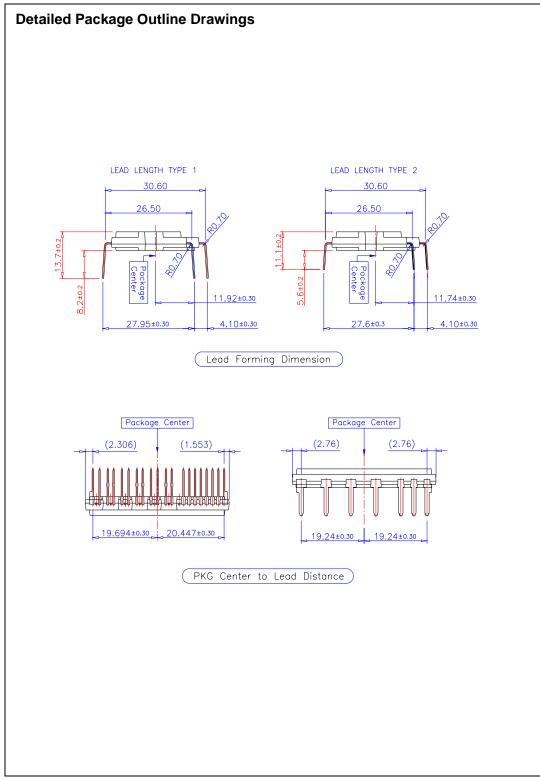


- P1: Normal operation IGBT ON and conducting current
- P2 : Over current detection
- P3: IGBT gate interrupt / Fault signal generation
- P4: IGBT is slowly turned off
- P5 : IGBT OFF signal
- P6: IGBT ON signal but IGBT cannot be turned on during the fault Output activation
- P7: IGBT OFF state
- P8: Fault Output reset and normal operation start

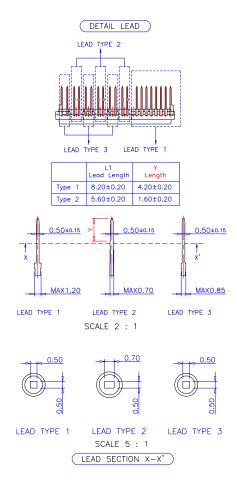
Fig. 7. Over Current Protection







Detailed Package Outline Drawings



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